

60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C (Note 9)
	$4.1 \text{m}\Omega$ @ $V_{GS} = 10V$	100A
60V	$6.3 \text{m}\Omega$ @ V _{GS} = 6V	81A
	$7m\Omega$ @ V _{GS} = 4.5V	77A

Features and Benefits

- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Low RDS(ON) Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher **Density End Products**
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free, "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

Description and Applications

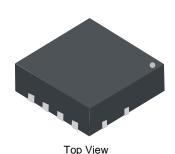
This MOSFET is designed to minimize the on-state resistance (RDS(ON)), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

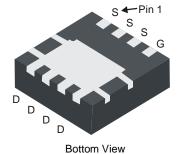
- Synchronous Rectification
- Motor Control
- **DC-DC Converters**
- **Power Management**

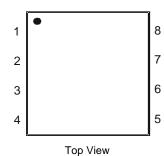
Mechanical Data

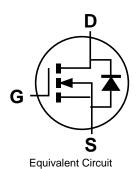
- Case: PowerDI®3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.029 grams (Approximate)

PowerDI3333-8









Ordering Information (Note 4)

Part Number	Case	Packaging
DMT6005LFG-7	PowerDI3333-8	2,000/Tape & Reel
DMT6005LFG-13	PowerDI3333-8	3,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



SK6 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 20 = 2020) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current (Notes 6 & 9) $V_{GS} = 10V$ $T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$		lo	100 80	А
Continuous Drain Current (Note 5) $V_{GS} = 10V$ $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		lo	18 14	А
Maximum Continuous Body Diode Forward Current (Note 6)	Is	100	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	400	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1	I _{SM}	400	Α	
Avalanche Current, L = 1mH	las	18.5	Α	
Avalanche Energy, L = 1mH	Eas	171	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25$ °C	PD	1.98	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	63	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	62.5	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	2.0	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

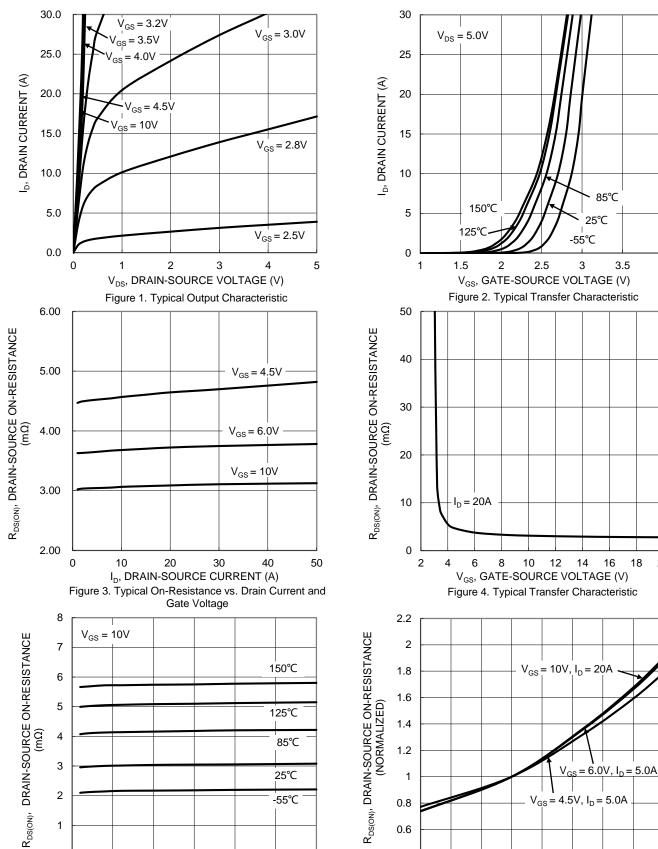
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage		_	_	±100	nA	Vgs = ±20V, Vps = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	1	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
	RDS(ON)	-	3.1	4.1	mΩ	V _G S = 10V, I _D = 20A	
Static Drain-Source On-Resistance		_	3.6	6.3	mΩ	Vgs = 6V, ID = 20A	
		_	4.4	7	mΩ	$V_{GS} = 4.5V, I_{D} = 20A$	
Diode Forward Voltage	V _{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)	_						
Input Capacitance	Ciss	_	3150	_		.,	
Output Capacitance	Coss	_	1036	_	pF	$V_{DS} = 30V$, $V_{GS} = 0V$, $f = 1MHz$	
Reverse Transfer Capacitance	Crss	_	69	_		T = TIMHZ	
Gate Resistance	Rg	_	0.7	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (VGS = 10V)	Qg	_	48.7	_			
Total Gate Charge (Vgs = 4.5V)	Qg	_	23.6	_			
Gate-Source Charge	Qgs	_	7.0	_	nC	$V_{DD} = 30V, I_{D} = 50A$	
Gate-Drain Charge	Qgd	_	11.2	_			
Turn-On Delay Time	t _{D(ON)}	_	7.3	_			
Turn-On Rise Time	t _R	_	11.3	_		$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	26.0	_	ns	$I_D = 30A, R_G = 3.3\Omega$	
Turn-Off Fall Time	t _F	-	11.0	_			
Bodyy Diode Reverse Recovery Time	trr	_	40.8	_	ns	1 204 4:/44 4004/	
Body Diode Reverse Recovery Charge	Q _{RR}	_	51.5	_	nC	$I_F = 30A$, di/dt = 100A/ μ s	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.
 Limited by Package. Notes:







I_D, DRAIN CURRENT (A) Figure 5. Typical On-Resistance vs. Drain Current and Temperature

15

T_J, JUNCTION TEMPERATURE (°C) Figure 6. On-Resistance Variation with Temperature

50

 $V_{GS} = 4.5V, I_D = 5.0A$

75

100

125

2

1

0

30

1

0.8

0.6

0.4

-50

25℃

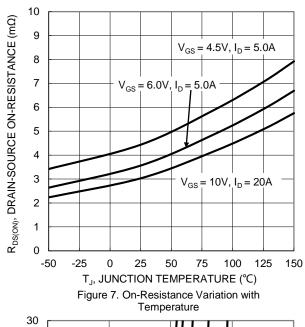
-55°C

25

20







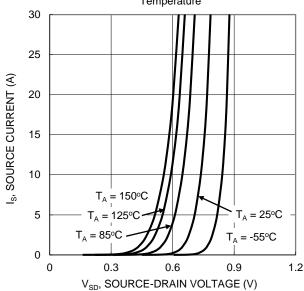
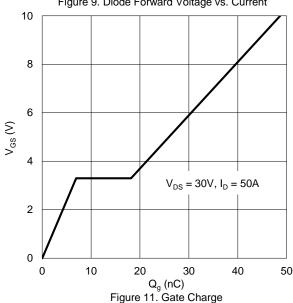


Figure 9. Diode Forward Voltage vs. Current



2 $V_{\text{GS(TH)}},$ GATE THRESHOLD VOLTAGE (V) 1.8 1.6 $I_D = 1mA$ 1.4 1.2 $I_{D} = 250 \mu A$ 1 8.0 0.6 0.4 -25 -50 0 25 50 75 100 125 150 T_J, JUNCTION TEMPERATURE (°C)

Figure 8. Gate Threshold Variation vs. JunctionTemperature

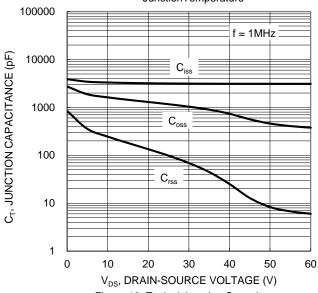
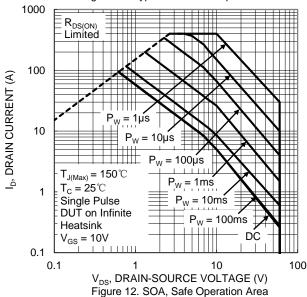


Figure 10. Typical Junction Capacitance





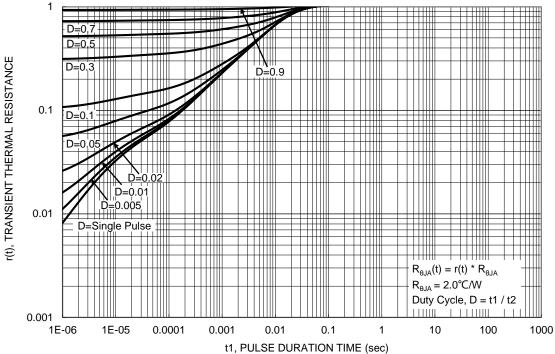


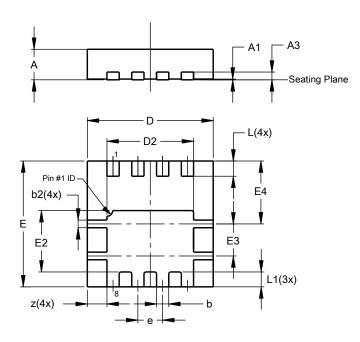
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

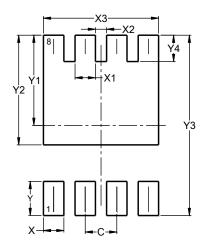


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
А3	-	-	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
ם	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	_	_	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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